#### NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE6080K uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

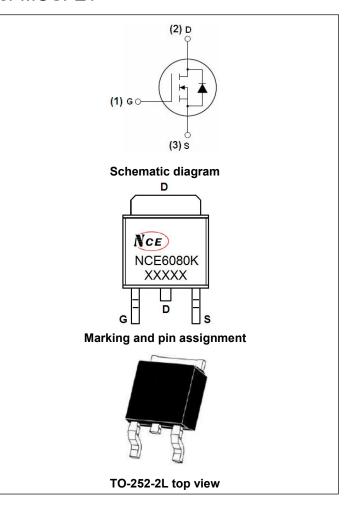
- V<sub>DS</sub> =60V,I<sub>D</sub> =80A
  - $R_{DS(ON)}$  <7m $\Omega$  @  $V_{GS}$ =10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

### **Application**

- PWM
- Load Switching

100% UIS TESTED!

100% ΔVds TESTED!



#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6080K	NCE6080K	TO-252-2L	-	-	-

## Absolute Maximum Ratings (T<sub>C</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	80	Α
Drain Current-Continuous(Tc=100°C)	I <sub>D</sub> (100°C)	56.5	Α
Pulsed Drain Current	I <sub>DM</sub>	320	Α
Maximum Power Dissipation	P <sub>D</sub>	110	W
Derating factor		0.73	W/℃
Single pulse avalanche energy (Note 5)	Eas	390	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

# NCE6080K

# **Thermal Characteristic**

Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	R <sub>eJC</sub>	1.36	°C/W
Thermal Resistance,Junction-to-Ambient <sup>(Note 2)</sup>	R <sub>0JA</sub>	60	°C/W

## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

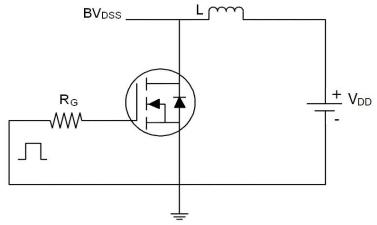
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	,	1	'	'		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	Igss	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			'			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	2	2.8	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	6	7	mΩ
Forward Transconductance	<b>G</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	20	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>		-	4000	-	PF
Output Capacitance	Coss	$V_{DS}=30V, V_{GS}=0V,$	-	290	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	210	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	8.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30V,R <sub>L</sub> =1 $\Omega$	-	7	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	40	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg	V 20VI 20A	-	90		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =30V,I <sub>D</sub> =20A,	-	9		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	18		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	80	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 20A	-	32	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	45	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negl	igible (tur	n-on is do	ominated b	y LS+LD

#### Notes:

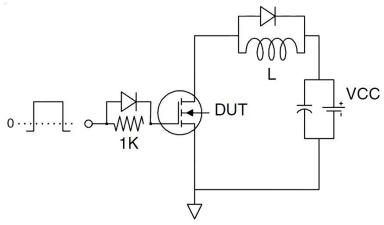
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width  $\leq 300 \mu s$ , Duty Cycle  $\leq 2\%$ .
- 4. Guaranteed by design, not subject to production
- **5.** E<sub>AS</sub> condition : Tj=25  $^{\circ}\text{C}$  ,V<sub>DD</sub>=20V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

## **Test circuit**

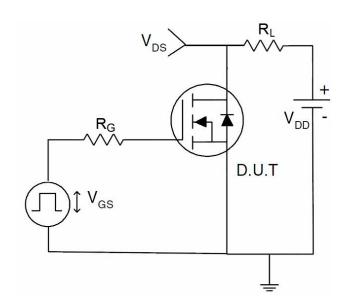
# 1) E<sub>AS</sub> Test Circuit



# 2) Gate Charge Test Circuit

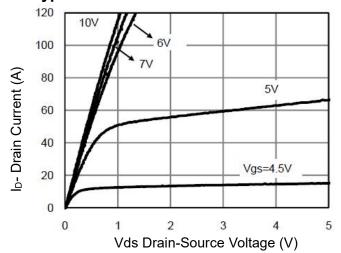


# 3) Switch Time Test Circuit

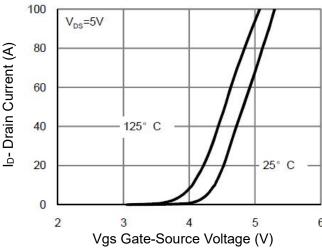




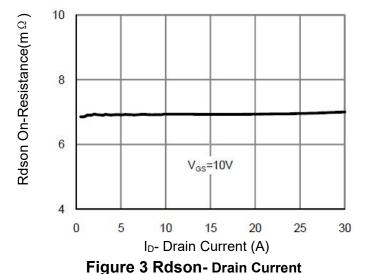
## Typical Electrical and Thermal Characteristics (Curves)



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 



2.2 Normalized On-Resistance V<sub>GS</sub>=10V 2 I<sub>D</sub>=20A 1.8 1.6 1.4 1.2 0.8 0 50 75 100 125 150 175 T<sub>J</sub>-Junction Temperature(°C)

Figure 4 Rdson-JunctionTemperature

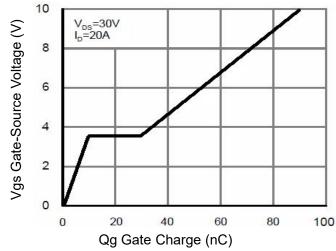


Figure 5 Gate Charge

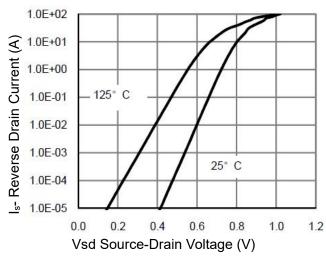


Figure 6 Source- Drain Diode Forward



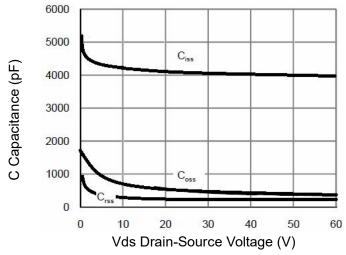


Figure 7 Capacitance vs Vds

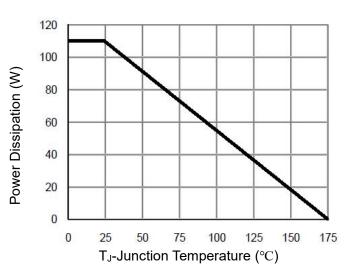
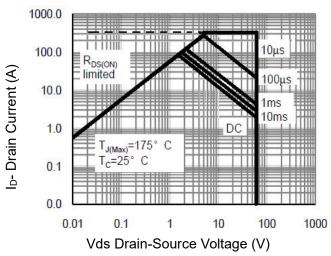
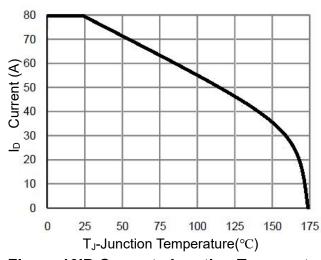


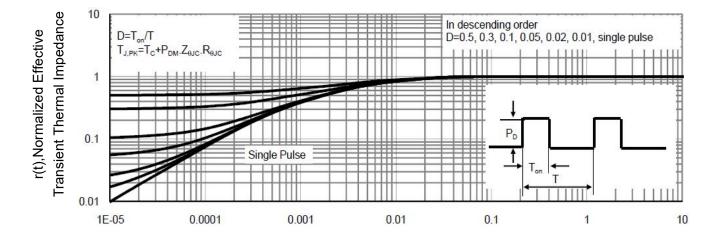
Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 



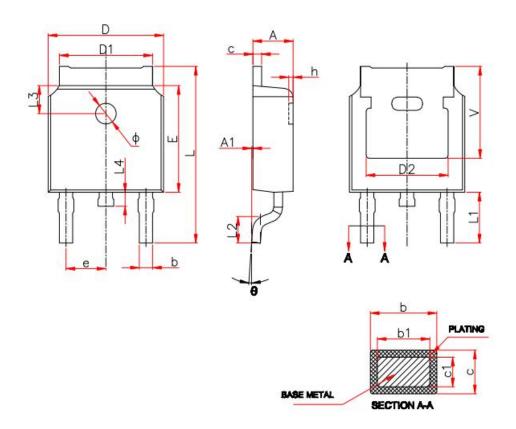
**Figure 10ID Current- Junction Temperature** 



Square Wave Pluse Duration(sec)

**Figure 11 Normalized Maximum Transient Thermal Impedance** 

# **TO-252 Package Information**



Cumbal	Millimeters		
Symbol -	Min.	Max.	
Α	2.20	2.40	
A1	0.00	0.13	
b	0.66	0.86	
b1	0.73	0.79	
С	0.46	0.58	
c1	0.50	0.52	
D	6.50	6.70	
D1	5.10	5.46	
D2	4.83 REF.		
Е	6.00	6.20	
е	2.19	2.39	
L	9.80	10.40	
L1	2.90 REF.		
L2	1.40	1.70	
L3	1.60 REF.		
L4	0.60	1.00	
Φ	1.10	1.30	
θ	0°	8°	

# NCE6080K

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